New Product

UH3B, UH3C & UH3D

Vishay General Semiconductor

Surface Mount Ultrafast Rectifier



DO-214AB (SMC)

FEATURES

- Low profile package
- Ideal for automated placement
- Oxide planar chip junction
- Ultrafast recovery times for high frequency RoHS
 COMPLIANT
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Solder dip 260 °C, 40 s
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

TYPICAL APPLICATIONS

For use in secondary rectification and freewheeling for ultrafast switching speeds of ac-to-ac and dc-to-dc converters in high temperature conditions for both consumer and automotive applications.

$\begin{tabular}{|c|c|c|c|} \hline PRIMARY CHARACTERISTICS \\ \hline I_{F(AV)} & 3.0 \ A \\ \hline V_{RRM} & 100 \ V, 150 \ V, 200 \ V \\ \hline I_{FSM} & 80 \ A \\ \hline t_{rr} & 25 \ ns \\ \hline V_F \ at \ I_F = 3.0 \ A & 0.75 \ V \\ \hline T_J \ max. & 175 \ ^{\circ}C \\ \hline \end{tabular}$

MECHANICAL DATA

Case: DO-214AB (SMC)

Epoxy meets UL 94V-0 flammability rating

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD22-B102

E3 suffix for consumer grade, meets JESD 201 class 1A whisker test, HE3 suffix for high reliability grade (AEC Q101 qualified), meets JESD 201 class 2 whisker test

Polarity: Color band denotes cathode end

MAXIMUM RATINGS ($T_A = 25 \text{ °C}$ unless otherwise noted)						
PARAMETER	SYMBOL	UH3B	UH3C	UH3D	UNIT	
Device marking code		HB	HC	HD		
Maximum repetitive peak reverse voltage	V _{RRM}	100 150 200		200	V	
Maximum average forward rectified current (Fig. 1)	I _{F(AV)}	2.5 ⁽¹⁾ 3.0 ⁽²⁾			A	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I _{FSM}	80			A	
Operating junction and storage temperature range	T _J , T _{STG}	- 55 to + 175			°C	

Notes:

(1) Free air, mounted on recommended copper pad area

(2) Units mounted on P.C.B. with 0.31 x 0.31" (8.0 x 8.0 mm) copper pad area

Document Number: 89109 Revision: 29-May-08 For technical questions within your region, please contact one of the following: PDD-Americas@vishay.com, PDD-Asia@vishay.com, PDD-Europe@vishay.com



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ELECTRICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted)							
PARAMETER	TEST CONDITIO	SYMBOL	TYP.	MAX.	UNIT		
Instantaneous forward voltage ⁽¹⁾	I _F = 1.5 A I _F = 3.0 A	T _A = 25 °C	VF	0.85 0.95	- 1.05	v	
	I _F = 1.5 A I _F = 3.0 A	T _A = 125 °C	۷F	0.65 0.75	- 0.90		
Reverse current ⁽²⁾	rated V _R	T _A = 25 °C T _A = 125 °C	I _R	- 15	- 100	μΑ	
Maximum reverse recovery time	I _F = 0.5 A, I _R = 1.0 A, I _{rr} = 0.25 A	$T_A = 25 \text{ °C}$ t_{rr}	t _{rr}	14	25	ns	
Typical reverse recovery time	$I_F = 1.0 \text{ A, } \text{dI/dt} = 50 \text{ A/}\mu\text{s}, \\ V_R = 30 \text{ V, } I_{rr} = 0.1 \text{ I}_{RM}$			23	40		
Typical softness factor (t _b /t _a)		S	1.0	-			
Typical reverse recovery current	I _F = 3.0 A, dl/dt = 200 A/μs, V _B = 200 V	T _A = 125 °C	I _{RM}	5.0	7.0	А	
Typical stored charge	-n		Q _{rr}	60	-	nC	
Typical junction capacitance	4.0 V, 1 MHz		CJ	42	-	pF	

Notes:

(1) Pulse test: 300 μs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width \leq 40 ms

THERMAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted)						
PARAMETER	SYMBOL	UH3B	UH3C	UH3D	UNIT	
Typical thermal resistance ⁽¹⁾	$R_{ hetaJA}$ $R_{ hetaJM}$	95 12			°C/W	

Note:

(1) Free air, mounted on recommended copper pad area. Thermal resistance R_{0JA} - junction to ambient, R_{0JM} - junction to mount

ORDERING INFORMATION (Example)						
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
UH3D-E3/57T	0.236	57T	850	7" diameter plastic tape and reel		
UH3D-E3/9AT	0.236	9AT	3500	13" diameter plastic tape and reel		
UH3DHE3/57T ⁽¹⁾	0.236	57T	850	7" diameter plastic tape and reel		
UH3DHE3/9AT ⁽¹⁾	0.236	9AT	3500	13" diameter plastic tape and reel		

Note:

(1) Automotive grade AEC Q101 qualified



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RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

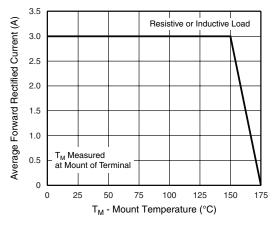


Figure 1. Maximum Forward Current Derating Curve

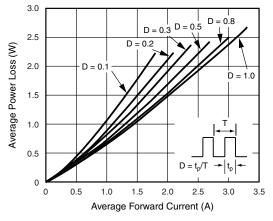


Figure 2. Forward Power Loss Characteristics

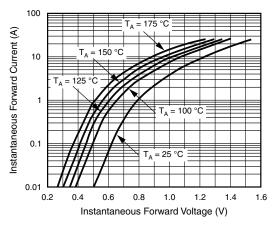
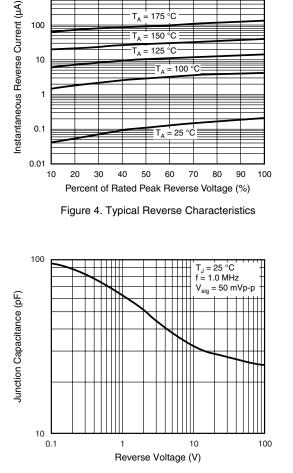


Figure 3. Typical Instantaneous Forward Characteristics

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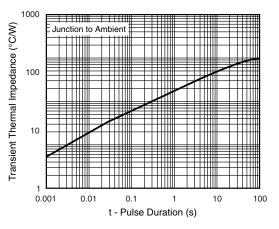
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Figure 5. Typical Junction Capacitance



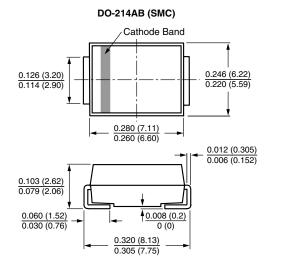


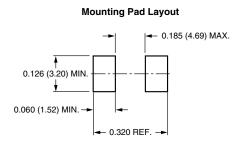
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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





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